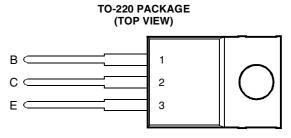
BOURNS®

- Designed for Complementary Use with TIP130, TIP131 and TIP132
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 1000 at 4 V, 4 A

This series is obsolete and not recommended for new designs.



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
	TIP135		-60	
Collector-base voltage (I _E = 0)	TIP136	V _{CBO}	-80	V
	TIP137		-100	
	T/P135		-60	
Collector-emitter voltage (I _B = 0)	TIP136	VCEO	-80	V
	TIP137		-100	
Emitter-base voltage		V _{EBO}	-5	V
Continuous collector current		I _C	-8	Α
Peak collector current (see Note 1)		I _{CM}	-12	Α
Continuous base current		Ι _Β	-0.3	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Unclamped inductive load energy (see Note 4)		½LI _C ²	75	mJ
Operating junction temperature range		T _j	-65 to +150	°C
Storage temperature range		T _{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

- NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.
 - 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
 - 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
 - 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = -20 V.

PRODUCT INFORMATION



electrical characteristics at 25°C case temperature

PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT				
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = -30 mA	I _B = 0	(see Note 5)	TIP135 TIP136 TIP137	-60 -80 -100			٧
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = -30 \text{ V}$ $V_{CE} = -40 \text{ V}$ $V_{CE} = -50 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		TIP135 TIP136 TIP137	-100		-0.5 -0.5 -0.5	mA
I _{CBO}	Collector cut-off current	~-	I _E = 0 I _E = 0	$T_{C} = 100^{\circ}C$ $T_{C} = 100^{\circ}C$ $T_{C} = 100^{\circ}C$	TIP135 TIP136 TIP137 TIP135 TIP136 TIP137			-0.2 -0.2 -0.2 -1 -1	mA
I _{EBO}	Emitter cut-off current	V _{EB} = -5 V	I _C = 0					-5	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = -4 V$ $V_{CE} = -4 V$	I _C = -1 A I _C = -4 A	(see Notes 5 and	16)	500 1000		15000	
V _{CE(sat)}	Collector-emitter saturation voltage	$I_B = -16 \text{ mA}$ $I_B = -30 \text{ mA}$	$I_C = -4 A$ $I_C = -6 A$	(see Notes 5 and	16)			-2 -3	٧
V_{BE}	Base-emitter voltage	V _{CE} = -4 V	I _C = -4 A	(see Notes 5 and	(6)			-2.5	V
C_{obo}	Output capacitance	$V_{CB} = -10 \text{ V}$	I _E = 0					200	pF
V _{EC}	Parallel diode forward voltage	I _E = -8 A	I _B = 0	(see Notes 5 and	(6)			-3.5	V

thermal characteristics

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.78	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

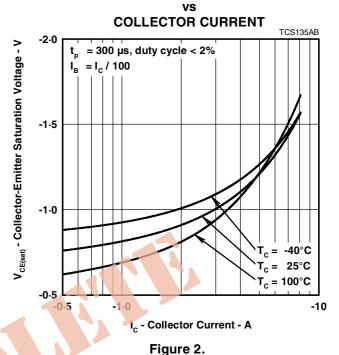
<sup>NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 μs, duty cycle ≤ 2%.
6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.</sup>

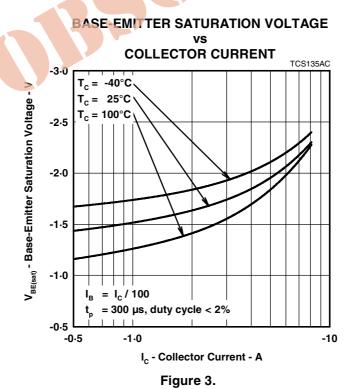
TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN VS COLLECTOR CURRENT TCS135AA Tc = -40°C Tc = 25°C Tc = 100°C Tc = 100°C V_{CE} = -4 V t_p = 300 µs, duty cycle < 2% I_C - Collector Current - A

Figure 1.

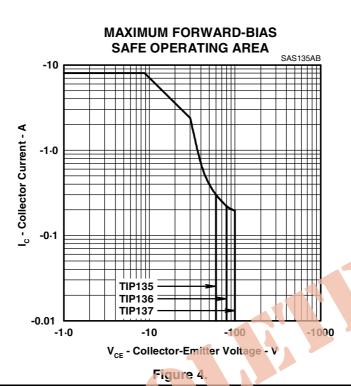
COLLECTOR-EMITTER SATURATION VOLTAGE





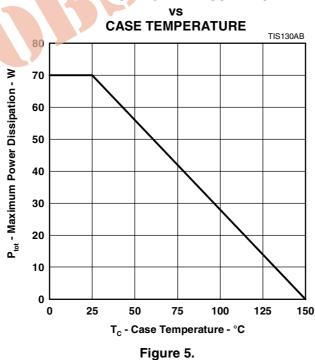
PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

MAXIMUM POWER DISSIPATION



PRODUCT INFORMATION